NOTES:
1. TEST PER ATP No. 230007.
2. DETECTOR TO BE CONCENTRIC WITHIN ±0.015 WITH RESPECT TO HEADER DIAMETER (409).
3. SPECIFICATIONS FOR Ge/SILICON BICOLOR DETECTOR (ROOM TEMPERATURE)
   - SILICON - ACTIVE SIZE (DIA): 5.0 mm
   - WAVELENGTH RANGE: 400 nm-1000 nm
   - RESPONSIVITY (850 nm) MIN: 0.45 A/W
   - SHUNT IMPEDANCE (22 °C): 40 kOhms
   - NEP (PEAK AND 300Hz): 1.0E-14 (W/Hz) TYPICAL

   GERMANIUM - ACTIVE SIZE (DIA): 3.0 mm
   - WAVELENGTH RANGE: 1100-1800 nm
   - RESPONSIVITY 1500 nm MTN: 0.60 A/W
   - SHUNT IMPEDANCE (22 °C): 35 kOhms
   - NEP (PEAK AND 300Hz): 6.0E-13 (W/Hz) TYPICAL

PACKAGE: TO-8
WINDOW MATERIAL: BOROSILICATE (GLASS)